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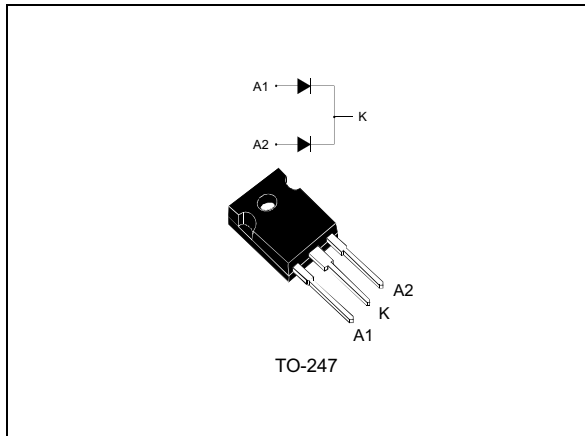
Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



Power Schottky Rectifier

Datasheet - production data



Description

Dual center tap Schottky rectifier suited for switch mode power supply and high frequency DC to DC converters. Packaged in TO-247, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.

Table 1. Device summary

Symbol	Value
$I_F(AV)$	2 x 30 A
V_{RRM}	45 V
$T_j(max.)$	175 °C
$V_F(max.)$	0.63 V

Features

- Very small conduction losses
- Negligible switching losses
- Extreme fast switching
- Low thermal resistance
- Avalanche capability specified

Characteristics

Table 2. Absolute ratings (limiting values, per diode)

Symbol	Parameter		Value	Unit
V _{RRM}	Repetitive peak reverse voltage		45	V
I _{F(RMS)}	RMS forward current		60	A
I _{F(AV)}	Average forward current δ = 0.5	T _c = 150 °C per diode	30	A
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal	400	A
I _{RRM}	Repetive peak reverse current	t _p = 2 μs square F = 1 kHz	1	A
I _{RSM}	Non repetitive peak reverse current	t _p = 100 μs square	3	A
P _{ARM}	Repetitive peak avalanche power	t _p = 1 μs T _j = 25 °C	10600	W
T _{stg}	Storage temperature range		- 65 to + 175	°C
T _j	Maximum operating junction temperature ⁽¹⁾		175	°C
dV/dt	Critical rate of rise or reverse voltage		10000	V/μs

1. $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. thermal resistances

Symbol	Parameter		Value	Unit
R _{th(j-c)}	Junction to case	Per diode	0.95	°C/W
		Total	0.55	
R _{th(c)}		Coupling	0.15	

When the diodes 1 and 2 are simultaneously:

$$\Delta T_j(\text{diode 1}) = P(\text{diode1}) \times R_{th(j-c)} (\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25\text{ }^\circ\text{C}$	$V_R = V_{RRM}$	-		500	μA
		$T_j = 125\text{ }^\circ\text{C}$		-	20	80	mA
$V_F^{(1)}$	Forward voltage drop	$T_j = 125\text{ }^\circ\text{C}$	$I_F = 30\text{ A}$	-	0.53	0.63	V
		$T_j = 25\text{ }^\circ\text{C}$	$I_F = 60\text{ A}$	-		0.84	
		$T_j = 125\text{ }^\circ\text{C}$	$I_F = 60\text{ A}$	-	0.68	0.78	

1. Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P + 0.48 \times I_{F(AV)} + 0.005 I_{F(RMS)}^2$$

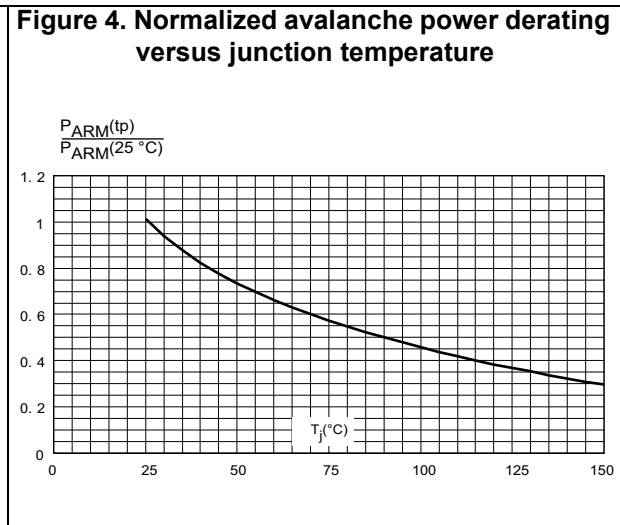
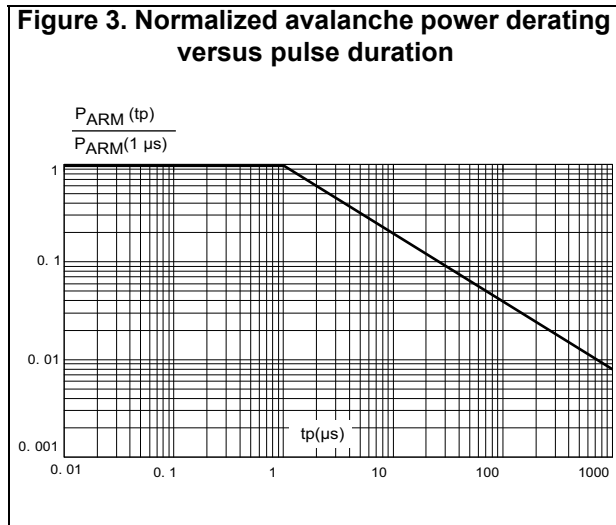
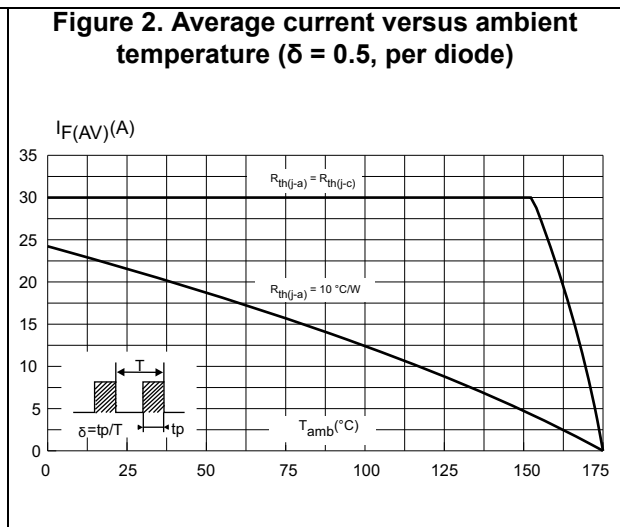
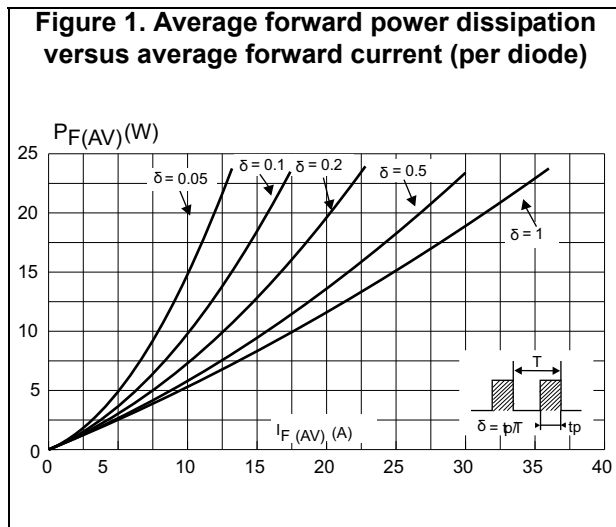


Figure 5. Non-repetitive surge peak forward current versus overload duration (maximum values, per diode)

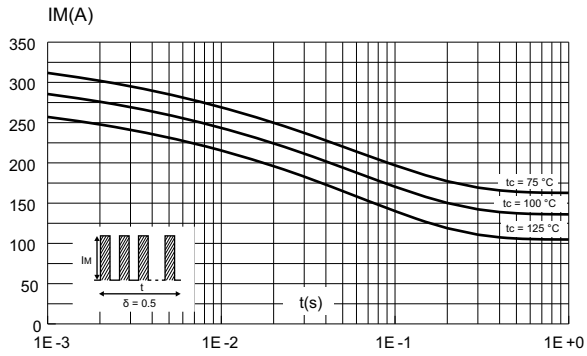


Figure 6. Relative variation of thermal transient impedance junction to case versus pulse duration

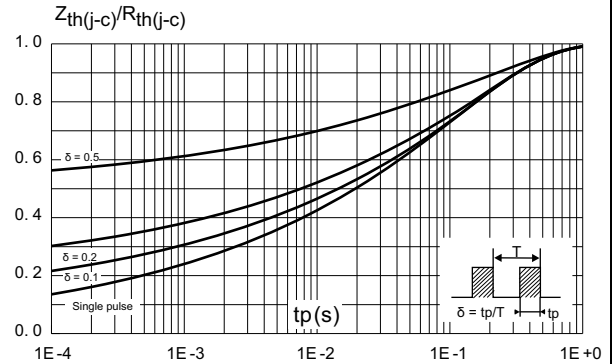


Figure 7. Reverse leakage current versus reverse voltage applied (typical values, per diode)

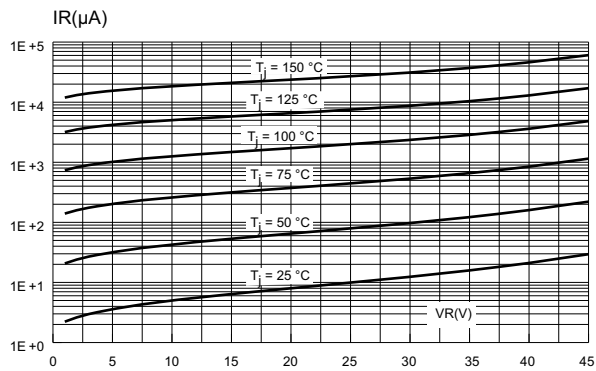
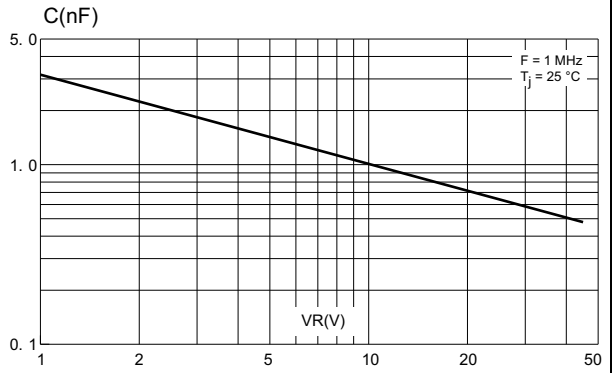
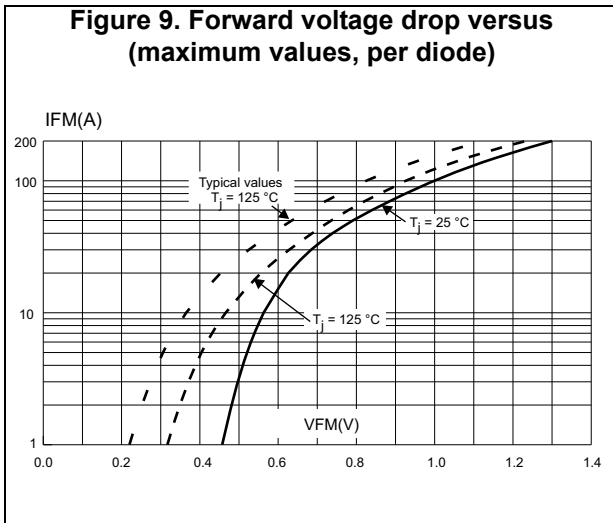


Figure 8. Junction capacitance versus reverse voltage applied (typical values, per diode)





1 Package information

- Cooling method: by conduction (C)
- Recommended torque value: 0.8 N.m.
- Maximum torque value: 1.0 N.m.
- Epoxy meets UL94, V0

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1.1 TO-247 package information

Figure 10. TO-247 package outline

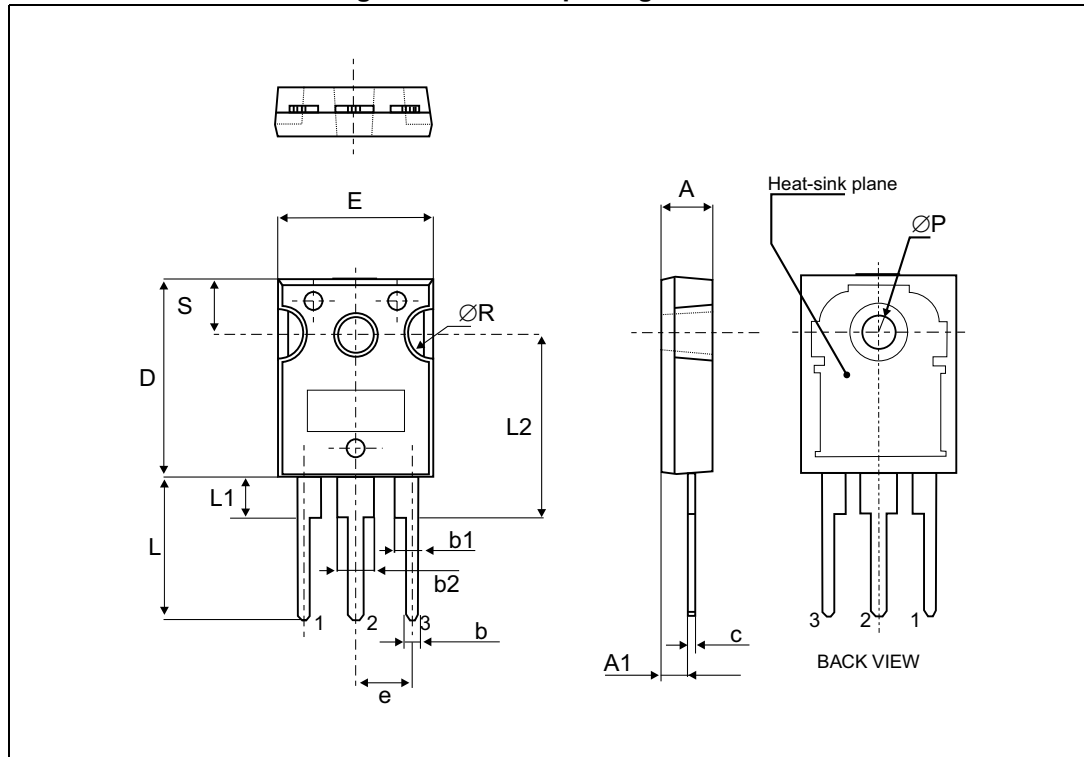


Table 5. TO-247 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Typ.	Min.	Max.	Typ.	Min.	Max.
A		4.85	5.15		0.191	0.203
A1		2.20	2.60		0.086	0.102
b		1.0	1.40		0.039	0.055
b1		2.0	2.40		0.078	0.094
b2		3.0	3.40		0.118	0.133
c		0.40	0.80		0.015	0.031
D		19.85	20.15		0.781	0.793
E		15.45	15.75		0.608	0.620
e	5.50	5.30	5.60		0.209	0.220
L		14.20	14.80		0.559	0.582
L1		3.70	4.30		0.145	0.169
L2	18.50			0.728		
ØP		3.55	3.65		0.139	0.143
ØR		4.50	5.50		0.177	0.217
S	5.50	5.30	5.70		0.209	0.224

1. Values in inches are converted from mm and rounded to 4 decimal digits.

2 Ordering information

Table 6. Ordering information

Type	Marking	Package	Weight	Base qty.	Delivery mode
STPS6045CW	STPS6045CW	TO-247	4.36 g.	30	Tube

3 Revision history

Table 7. Document revision history

Date	Revision	Changes
24-Jul-2012	7	
11-Dec-2015	8	Format updated to current standard. Update of Table 2 and Table 3 and Table 5 . Update of Figure 2 . Remove of figure 5.2.

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